

**GATE / PSU<sub>s</sub>**

**ELECTRONICS  
ENGINEERING-ECE**

**STUDY MATERIAL**

**ANALOG ELECTRONICS**

 **ENGINEERS**  
INSTITUTE OF INDIA



**ELECTRONICS ENGINEERING**  
**GATE & PSU<sub>s</sub>**

**STUDY MATERIAL**

**ANALOG ELECTRONICS**

**CONTENT**

1.	DIODE APPLICATION .....	03-29
2.	OPERATIONAL AMPLIFIER.....	30-46
3.	TRANSISTOR BIASING AND STABILIZATION .....	47-60
4.	BJT AT LOW FREQUENCY .....	61-73
5.	BJT AT HIGH FREQUENCY .....	74-93
6.	FET AMPLIFIER .....	94-101
7.	OSCILLATOR .....	102-112
8.	FEEDBACK AMPLIFIER .....	113-123
9.	POWER AMPLIFIER .....	124-131
10.	MULTI VIBRATORS AND WAVE SHAPING CIRCUITS .....	132-138
11.	ANALOG CIRCUITS GATE questions (ELECTRICAL) .....	139-173
12.	ANALOG ELECTRONICS IES Objective( ELECTRICAL).....	174-222

# CHAPTER-1

## DIODE APPLICATION

**1. Rectifier:** A diode rectifier (alternating to unidirectional converter) forms an essential building block of the dc power supplies required to electronic equipment.



Alternating (DC value = 0)

Unidirectional (Pulsating DC)  
(+ve DC value)

### Important Terms

**1. Ripple Factor:** 
$$r = \frac{\text{RMS value of AC component}}{\text{DC value}}$$

$$r = \frac{V_{ac\ rms}}{V_{dc}}$$

$$= \frac{\sqrt{V_{rms}^2 - V_{dc}^2}}{V_{dc}} = \sqrt{\left(\frac{V_{rms}}{V_{dc}}\right)^2 - 1}$$

$$V_{rms} = \sqrt{V_{ac^2\ rms} + V_{a^2c}}$$

$$\left[ \text{Form factor (F)} = \frac{\text{RMS value}}{\text{DC value}} = \frac{V_{rms}}{V_{dc}} \right]$$

Hence, 
$$r = \sqrt{F^2 - 1}$$

**Note:** Ideal value  $r = 0$ ,  $F = 1$  (AC component = 0)

**2. Crest Factor:** 
$$C = \frac{\text{Peak value}}{\text{RMS value}}$$

**3. Ripple Voltage:** Ripple voltage is defined as deviation of output voltage from its DC value



Output of rectifier  $\Rightarrow$  Pulsating DC

$$\text{DC value} = V_{dc}$$

$$\text{RMS value} = V_{rms}$$

**4. PIV (Peak Inverse Voltage)**

It is maximum voltage applied to diode in reverse bias condition and decide voltage handling capacity of diode circuit.

**Note:** PIV should be low.

**5. Transformer utilization factor:** It shows the degree of utilization of the transformer in rectifier circuit.

It must be very high and decide cost of circuit

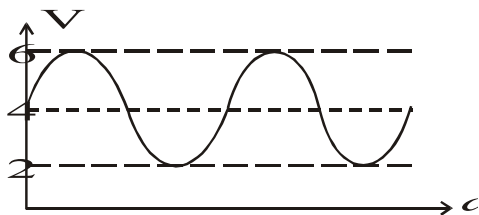
## Output Rectifier

$$V = V_{DC} + V_{AC}$$

$$V_{rms} = \sqrt{(V_{DC})^2 + (V_{AC_{rms}})^2}$$

$$\Rightarrow V_{AC_{rms}} = \sqrt{V_{rms}^2 - V_{DC}^2}$$

**Example:** Let  $V = 4 + 2 \sin \omega t$



- $V_{DC} = 4$
- $V_{AC_{rms}} = \frac{2}{\sqrt{2}}$
- $V_{rms} = \sqrt{4^2 + \left(\frac{2}{\sqrt{2}}\right)^2} = \sqrt{16 + 2} = \sqrt{18}$
- **Ripple Factor (r)**  $= \frac{V_{AC_{rms}}}{V_{dc}} = \frac{\frac{2}{\sqrt{2}}}{4} = \frac{1}{2\sqrt{2}} = 0.35$
- **Form Factor**

$$F = \frac{V_{rms}}{V_{DC}} = \frac{\sqrt{18}}{4} = 1.06$$

**Rectifier**

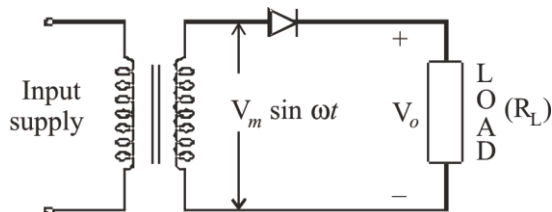
1. Half wave rectifier
2. Full wave rectifier

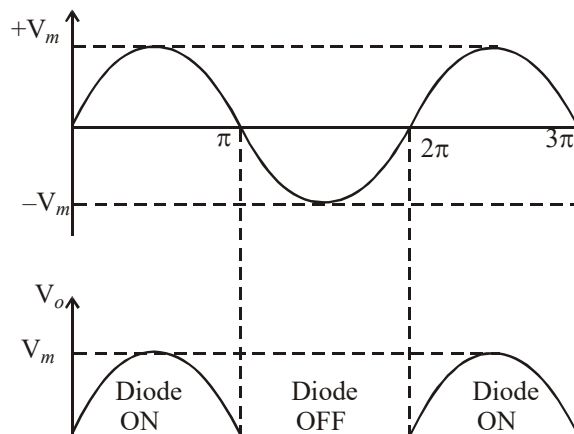
(a) Centre taped rectifier

(b) Bridge rectifier

- **Half Wave Rectifier**

The half wave rectifier utilizes alternate half cycles of the input signal.





⇒ During +ve half cycle of supply voltage diode on and during -ve half it is off.

$$1. V_{\text{avg}} = V_{\text{DC}}$$

$$= \frac{1}{2\pi} \int_0^{\pi} V_m \sin \omega t \, d(\omega t) = \frac{V_m}{\pi}$$

$$2. V_{\text{rms}} = \left[ \frac{1}{2\pi} \int_0^{\pi} V_m^2 \sin^2 \omega t \, d(\omega t) \right]^{\frac{1}{2}} = \frac{V_m}{2}$$

### 3. Form Factor

$$F = \frac{V_{\text{rms}}}{V_{\text{DC}}} = \frac{\frac{V_m}{2}}{\frac{V_m}{\pi}} = \frac{\pi}{2} = 1.58$$

### 4. Ripple Factor

$$r = \sqrt{F^2 - 1} = \sqrt{\left(\frac{\pi}{2}\right)^2 - 1} = 1.21$$

### 5. Crest Factor:

$$C = \frac{\text{Peak value}}{\text{RMS value}} = \frac{V_m}{\frac{V_m}{2}} = 2$$

### 6. Rectifier Efficiency:

$$\eta = \frac{\text{DC output power}}{\text{AC input power}} \times 100 = \frac{P_{dc}}{A_{AC}}$$

$$P_{dc} = V_o I_o = \frac{V_m}{\pi} \times \frac{I_m}{\pi} = \frac{V_m I_m}{\pi^2}$$

$$\left( I_m = \frac{V_m}{R_L} \right)$$

$$\text{RMS output voltage } V_{\text{rms}} = \frac{V_m}{2}$$

$$\text{RMS output current } I_{\text{rms}} = \frac{V_{\text{rms}}}{R_L} = \frac{V_m}{2R_L} = \frac{I_m}{2}$$

$$P_{ac} = V_{rms} I_{rms} = \frac{V_m}{2} \frac{I_m}{2} = \frac{V_m I_m}{4}$$

$$\eta(\%) = \frac{P_{dc}}{P_{ac}} = \frac{\frac{V_m I_m}{\pi^2}}{\frac{V_m I_m}{4}} = \frac{4}{\pi^2} = 40.53\%$$

$$7. \text{TUF} : = \frac{P_{dc}}{\text{VA rating of transformer}} = \frac{\frac{V_m I_m}{\pi^2}}{\frac{V_m I_m}{2\sqrt{2}}} = 0.286$$

Voltage is available for full time period and current is available for half of time period

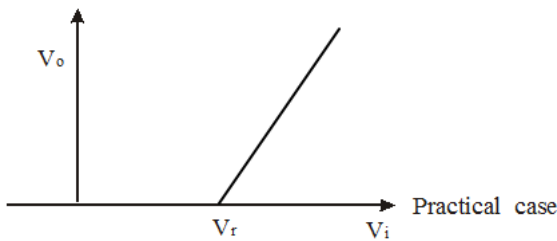
**Note:** Transformer is under utilized

8. **PIV:** Peak inverse voltage =  $V_m$

9. **Ripple Frequency:** Source frequency

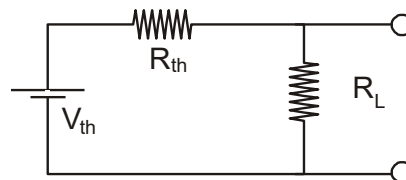
$$f_r = f_s$$

⇒ **Transfer curve of H.W.R.** (Diode is assumed ideal)



$V_i$	D	$V_o$
$V_i > 0$	ON	$V_i$
$V_i < 0$	OFF	0

Thevenin equivalent of half wave rectifier



$$I_{dc} = \frac{V_{TH}}{R_{TH} + R_L}$$

$$I_L = \frac{V_m \sin \omega t - V_r}{R_S + R_F + R_L} \cong \frac{V_m \sin \omega t}{R_S + R_F + R_L}$$

$$I_{dc} = \frac{1}{2\pi} \int_0^\pi I_L d(\omega t) \quad I'_m \sin \omega t \text{ where } I'_m = \frac{V_m}{R_S + R_F + R_L}$$

$$I_{dc} = \frac{1}{2\pi} \int_0^\pi I_L d(\omega t) = \frac{1}{2\pi} \int_0^\pi I'_m \sin(\omega t) d(\omega t)$$

$$= \left( \frac{I'_m}{\pi} \right) = \frac{V_m / \pi}{R_S + R_F + R_L} = \left( \frac{V_{Th}}{R_{Th} + R_L} \right)$$

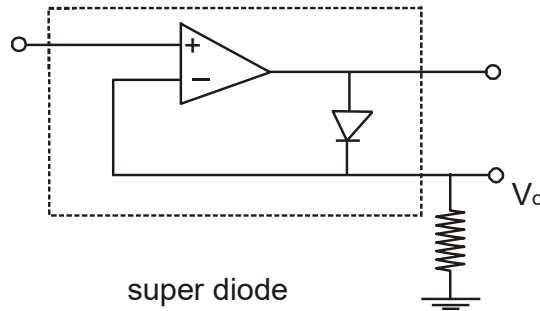
Thus  $V_{Th} = \frac{V_m}{\pi}$

$R_{Th} = R_S + R_F$

**Drawbacks :**

- Excessive ripple factor =1.21
- Low rectifier efficiency
- Low TUF
- d.c. Saturation of transformer secondary

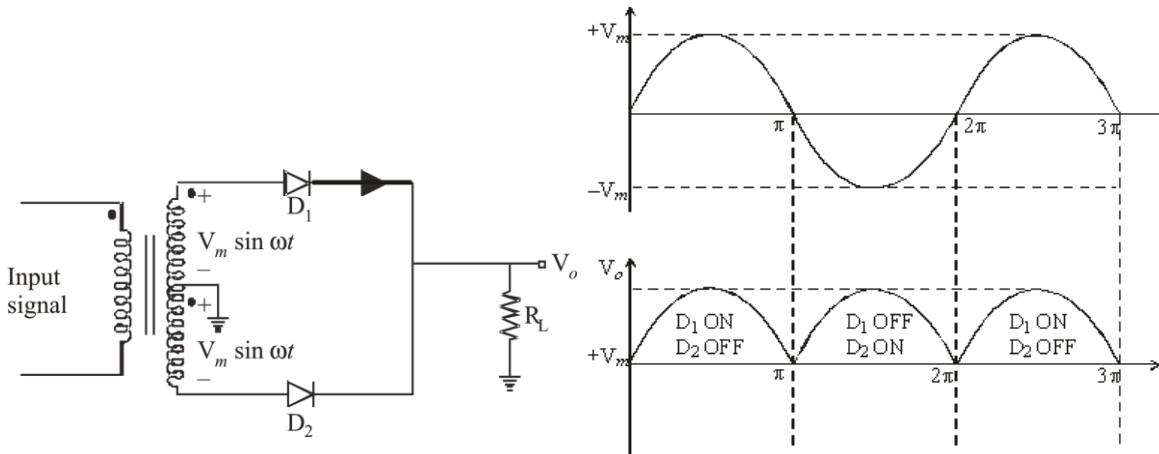
**Precision Half wave rectifier :**



**10. Full Wave Rectifier**

In the full wave rectifier, rectification takes place for both the half cycle of input signal.

**1. Centre Tapped F.W.R. (Using Ideal Diodes)**





**Note:** Ripple frequency = 2 (source frequency)

$$\boxed{f_r = 2f_s}$$

**(i) Average Value**

$$V_{\text{average}} = V_{\text{DC}} = \frac{1}{\pi} \int_0^{\pi} V_m \sin \omega t \cdot d(\omega t) = \frac{2V_m}{\pi}$$

**(ii) RMS Value**

$$V_{\text{rms}} = \left[ \frac{1}{\pi} \int_0^{\pi} V_m^2 \sin^2 \omega t \cdot d(\omega t) \right]^{\frac{1}{2}} = \frac{V_m}{\sqrt{2}}$$

**(iii) Form Factor**

$$F = \frac{V_{\text{rms}}}{V_{\text{DC}}} = \frac{\frac{V_m}{\sqrt{2}}}{\frac{2V_m}{\pi}} = \frac{\pi}{2\sqrt{2}} = 1.11$$

**(iv) Ripple Factor**

$$r = \sqrt{F^2 - 1} = \sqrt{\left(\frac{\pi}{2\sqrt{2}}\right)^2 - 1} = 0.48$$

**(v) Crest Factor**

$$C = \frac{V_m}{\frac{V_m}{\sqrt{2}}} = \sqrt{2}$$

**(vi) Rectifier Efficiency**

$$\eta\% = \frac{P_{dc}}{P_{ac}} \times 100 = \frac{4}{\pi^2} \frac{V_m I_m}{\left(\frac{V_m I_m}{2}\right)}$$

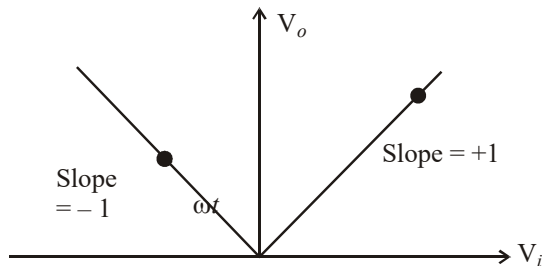
$$= \frac{8}{\pi^2} \quad \left( I_m = \frac{V_m}{R_L} \right)$$

$$\text{(vii) TUF} = \frac{P_{dc}}{\text{VA Rating of transformer}} = \frac{\frac{4}{\pi^2} V_m I_m}{0.6035 V_m I_m} = 0.672$$

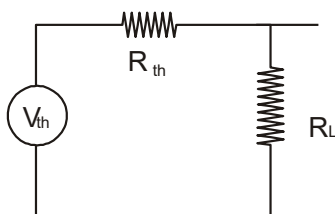
**Note:** In FWR case utilization of transformer takes place in both +ve and -ve half hence TUF increases.

**(viii) PIV** =  $2V_m$  ; Higher PIV is disadvantages to circuit as it effect diode operation.

Transfer Curve of FWR



Thevenin equivalent of full wave rectifier



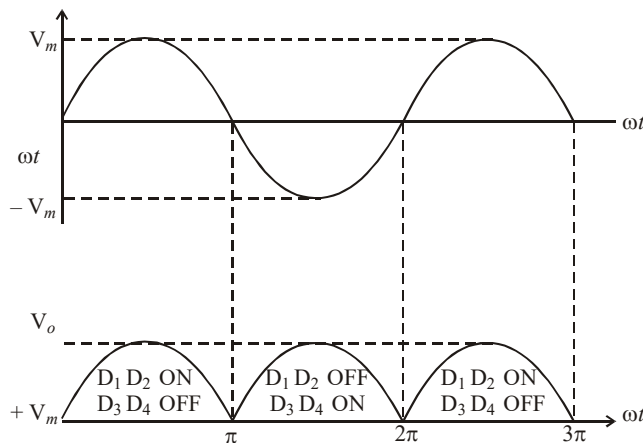
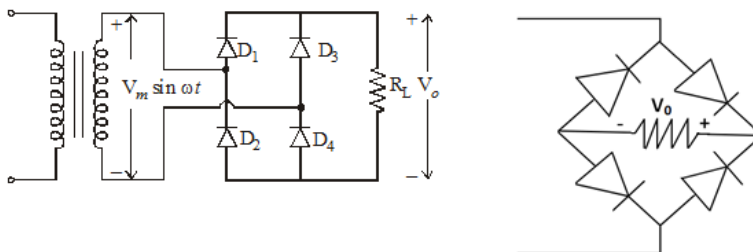
$$I_{th} = \frac{V_{th}}{R_L + R_{th}}$$

$$I_L = \frac{V_m \sin \omega t - V_r}{R_S + R_F + R_L} \cong \frac{V_m \sin \omega t}{R_S + R_F + R_L} = I'_m \sin \omega t \quad \therefore I'_m = \frac{V_m}{R_S + R_F + R_L}$$

$$I_{dc} = \frac{1}{2\pi} \int_0^\pi I_L d(\omega t) = \frac{2I'_m}{\pi} = \frac{2V_m / \pi}{R_S + R_F + R_L}$$

$$V_{th} = \frac{2V_m}{\pi} \quad R_{th} = R_S + R_F$$

2. Bridge Type FWR (Using Ideal Diode):



Floating resistance may acquire stray charge from environment.

(i) **Average value:**  $V_{\text{average}} = V_{\text{DC}} = \frac{2V_m}{\pi}$

(ii) **RMS value:**  $V_{\text{rms}} = \frac{V_m}{\sqrt{2}}$

(iii) **Form factor:**  $F = \frac{\pi}{2\sqrt{2}} = 1.11$

(iv) **Ripple factor:**  $r = 0.48$

(v) **Rectification efficiency** = 81.06%

**Note:** As waveform is same for centre tapped and bridge type FWR hence above (v) quantities are same.

(vi) **TUF:** TUF = 0.812

**Note:** Transformer is properly utilized.

(vii) **PIV** =  $V_m$

### Key Points:

(i) Both full wave rectifiers are better than the half wave rectifier in so far as voltage ripple factor, rectification efficiency, TUF and crest factor are concerned.

(ii) TUF of bridge type FWR is better than centre tapped FWR therefore transformers required in the centre tapped FWR is bulky.

(iii) PIV of diodes in bridge rectifier is half of that of the diodes used in centre tapped FWR.

(iv) Overall, a bridge rectifier using four diodes is more economical.

### Filter Circuits:

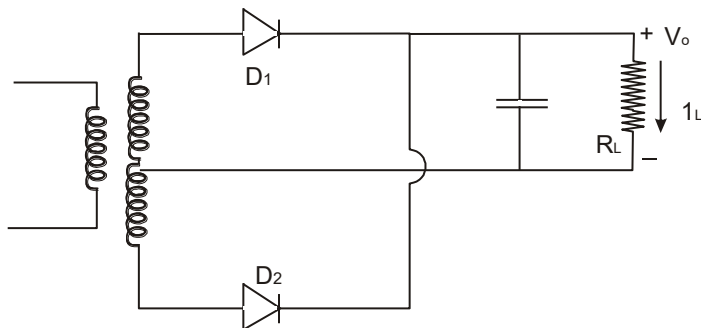
⇒ As the output of the rectifier circuit is pulsating DC containing AC and DC component filter circuits are used to suppress the AC component.

⇒ It reduces ripple factor to negligible value.

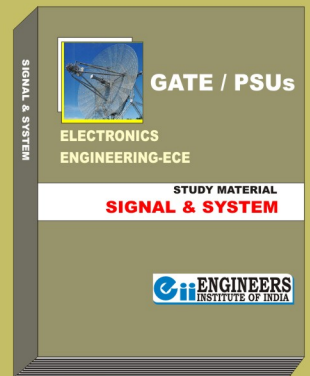
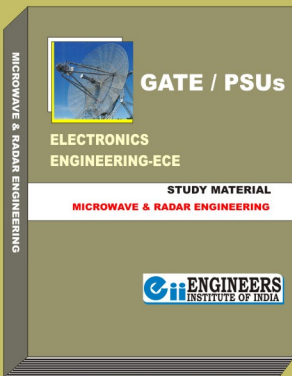
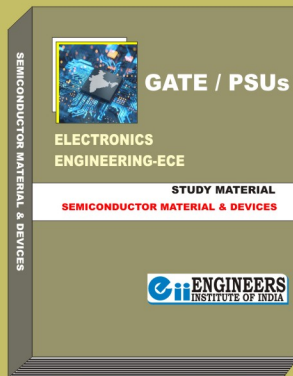
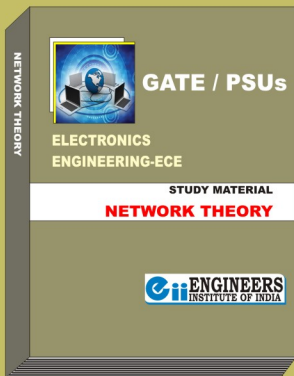
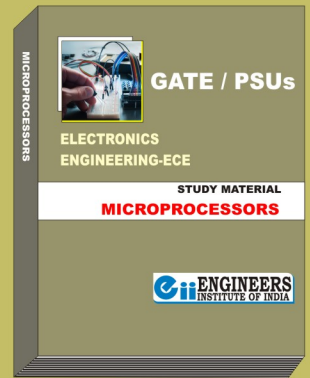
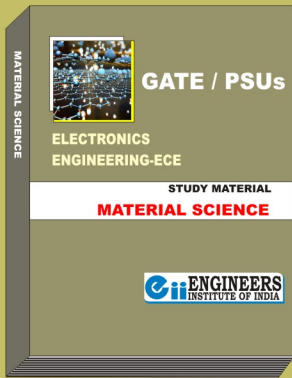
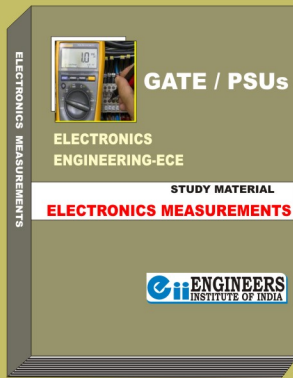
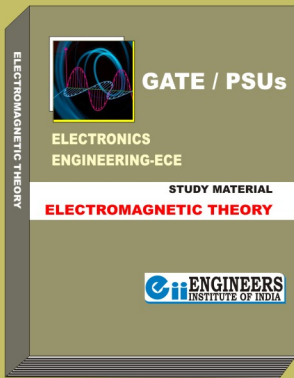
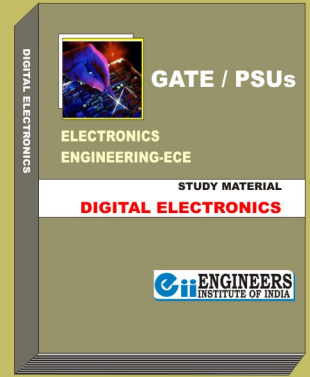
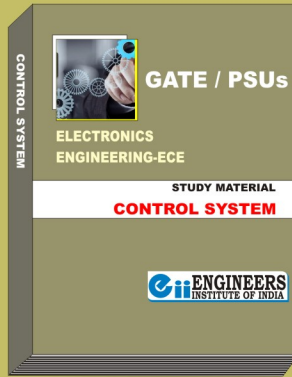
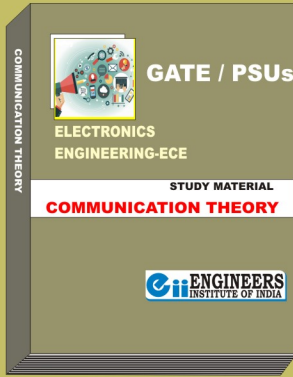
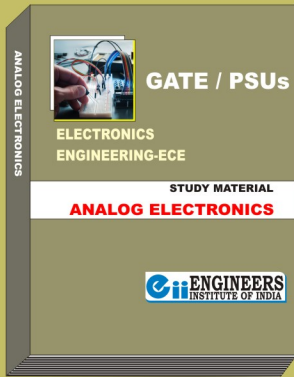
⇒ Important components of the filters are capacitor and inductor.

### Types of Filter Circuit:

#### 1. C Filter



# Published Books



Classroom Batches

Online Classes

Postal Course Classes

Online Test Series

Office: 58B, Kalu Sarai Near Hauz Khas Metro Station New Delhi-16

Helpline: 9990657855 , 9990357855

[www.engineersinstitute.com](http://www.engineersinstitute.com)